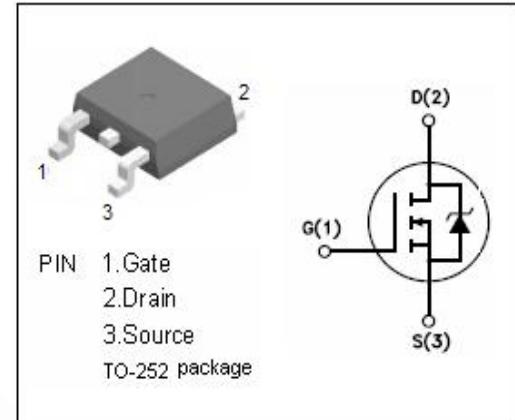




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**Isc N-Channel MOSFET Transistor****STD10NM60N****• FEATURES**

- With To-252(DPAK) package
- Low input capacitance and gate charge
- Low gate input resistance
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

**• APPLICATIONS**

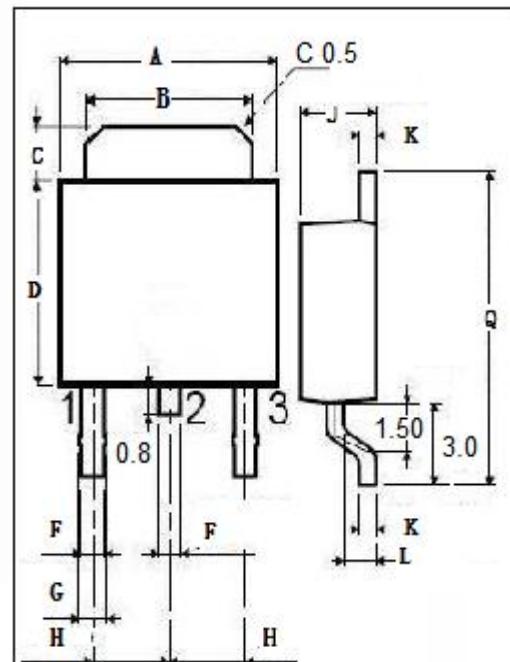
- Switching applications

**• ABSOLUTE MAXIMUM RATINGS( $T_a=25^\circ\text{C}$ )**

SYMBOL	PARAMETER	VALUE	UNIT
$V_{DSS}$	Drain-Source Voltage	600	V
$V_{GSS}$	Gate-Source Voltage	$\pm 25$	V
$I_D$	Drain Current-Continuous@ $T_c=25^\circ\text{C}$ $(T_J=175^\circ\text{C})$	10 5	A
$I_{DM}$	Drain Current-Single Pulsed	32	A
$P_D$	Total Dissipation @ $T_c=25^\circ\text{C}$	70	W
$T_{ch}$	Max. Operating Junction Temperature	150	$^\circ\text{C}$
$T_{stg}$	Storage Temperature	-55~150	$^\circ\text{C}$

**• THERMAL CHARACTERISTICS**

SYMBOL	PARAMETER	MAX	UNIT
$R_{th(ch-c)}$	Channel-to-case thermal resistance	1.79	$^\circ\text{C}/\text{W}$
$R_{th(ch-b)}$	Thermal resistance junction-pcb max	50	$^\circ\text{C}/\text{W}$



DIM	mm	
	MIN	MAX
A	6.40	6.60
B	5.20	5.40
C	1.15	1.35
D	5.70	6.10
F	0.65	
G	0.75	
H	2.10	2.50
J	2.10	2.40
K	0.40	0.60
L	0.90	1.10
Q	9.90	10.1



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**Isc N-Channel MOSFET Transistor****STD10NM60N****ELECTRICAL CHARACTERISTICS** $T_c=25^\circ\text{C}$  unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNIT
$BV_{DSS}$	Drain-Source Breakdown Voltage	$V_{GS}=0\text{V}; I_D= 1\text{mA}$	600			V
$V_{GS(\text{th})}$	Gate Threshold Voltage	$V_{DS}= \pm 25\text{V}; I_D=0.25\text{mA}$	2		4	V
$R_{DS(\text{on})}$	Drain-Source On-Resistance	$V_{GS}= 10\text{V}; I_D=4\text{A}$		60	65	$\text{m}\Omega$
$I_{GSS}$	Gate-Source Leakage Current	$V_{GS}= \pm 25\text{V}; V_{DS}= 0\text{V}$			$\pm 0.1$	$\mu\text{A}$
$I_{DSS}$	Drain-Source Leakage Current	$V_{DS}= 600\text{V}; V_{GS}= 0\text{V}; T_J=25^\circ\text{C}$ $T_J=125^\circ\text{C}$			1 100	$\mu\text{A}$
$V_{SDF}$	Diode forward voltage	$I_{SD}=8\text{A}, V_{GS} = 0 \text{ V}$			1.3	V